RB751S-40

200mW SOD-523 SURFACE MOUNT Very Small Outline Flat Lead Plastic Package Schottky Barrier Diode



Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
P _D	Power Dissipation	200	mW	
T _{STG}	Storage Temperature Range	-55 to +125	5 °C	
TJ	Operating Junction Temperature	+125	°C	
V_{RM}	Peal Reverse Voltage	40	V	
V_{R}	Reverse Voltage	30	V	
I _F	Forward Current	50	mA	
I _{FSM}	Non-Repetitive Peak Forward Current (at 8.3ms single half sine-wave)	200	mA	

These ratings are limiting values above which the serviceability of the diode may be impaired.

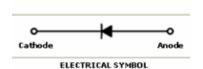
Specification Features:

- Low Forward Voltage Drop
- Flat Lead SOD-523 Small Outline Plastic Package
- Extremely Small SOD-523 Package
- Surface Device Type Mounting
- RoHS Compliant
- Green EMC
- Matte Tin(Sn) Lead Finish
- Band Indicates Cathode

Green Product



SOD-523 Flat Lead



DEVICE MARKING CODES:

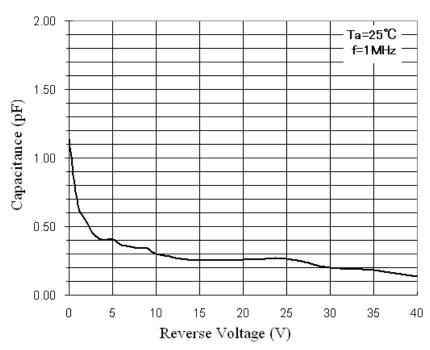
Device Type	Device Marking
RB751S-40	4B

Electrical Characteristics $T_A = 25$ °C unless otherwise noted

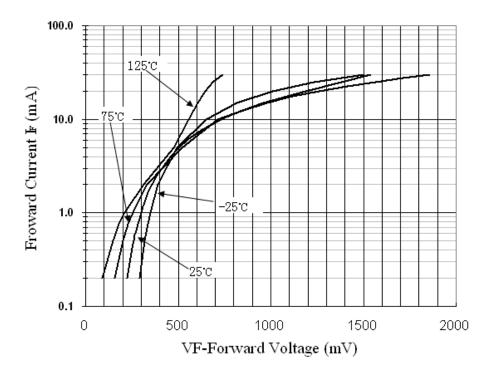
Symbol	Parameter	Test Condition	Limits		Unit
			Min	Max	Offic
Ву	Breakdown Voltage	I _R =10µA	30		Volts
I _R	Reverse Leakage Current	V _R =30V		0.5	μA
V _F	Forward Voltage	I _F =1mA		0.37	Volts

Typical Performance Characteristics

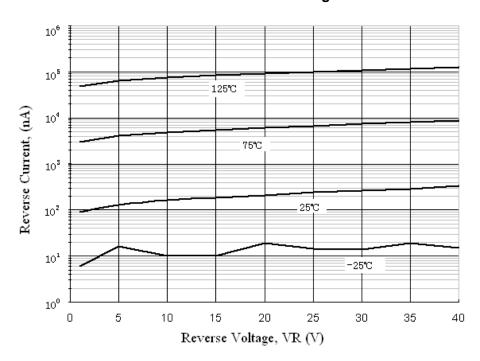
Total Capacitance



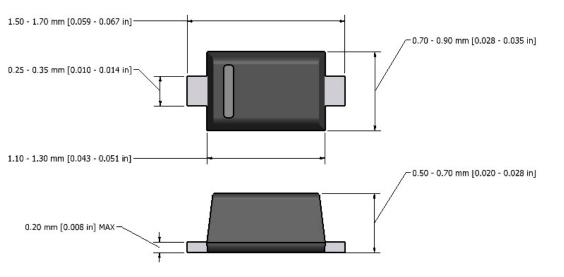
Forward Voltage vs Ambient Temperature



Reverse Current vs Reverse VoltageReverse



Flat Lead SOD-523 Package Outline



Note: Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.